	Туре	L #	Hits	Search Text	DBs	Time Stamp	Comment s
1	BRS	L1	11	kajita near yoko.in.	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM TDB	2004/02/1 0 17:33	
2	BRS	L2	512	438/243.ccls.	USPA T; US-P GPUB; EPO; JPO; DERW ENT; IBM_ TDB	2004/02/1 0 17:42	
3	BRS	L3	3846	(oxidation) near25 (silicon near film)	USPA T; US-P GPUB; EPO; JPO; DERW ENT; IBM_ TDB	2004/02/1 0 17:43	
4	BRS	L4	51	(oxidation) near25 (silicon near film) near25 (fill\$3)	USPA T; US-P GPUB; EPO; JPO; DERW ENT; IBM_ TDB	2004/02/1 0 17:47	

	Туре	L	#	Hits	Search Text	DBs	Time Stamp	Comment
5	BRS	L5		70	(oxidation) near25 (silicon near film or soi) near25 (fill\$3)	USPA T; US-P GPUB; EPO; JPO; DERW ENT; IBM_ TDB	2004/02/1 0 17:48	
6	BRS	L6		35	(oxidation) near25 (silicon near film or soi) near25 (fill\$3) near25 (substrate)	USPA T; US-P GPUB ; EPO; JPO; DERW ENT; IBM TDB	2004/02/1 0 17:51	
7	BRS	L7		32	(oxidation) near25 (silicon near film or soi) near25 (buried near oxide) near25 (substrate)	USPA T; US-P GPUB; EPO; JPO; DERW ENT; IBM_ TDB	2004/02/1 0 17:56	
8	BRS	L8		873	(oxidation) near25 (silicon near film or soi) near25 (oxide or box) near25 (substrate)		2004/02/1 0 18:21	

	Туре	L #	Hits	Search Text	DBs	Time Stamp	Comment s
9	BRS	L9	433	(oxidation) near25 (sede near wall\$1 or sidewall\$1) near25 (oxide or box) near25 (substrate)	ш. О,	2004/02/1 0 18:22	
10	BRS	L10	708	(oxidation) near25 (side near wall\$1 or sidewall\$1) near25 (oxide or box) near25 (substrate)	TT ()	2004/02/1 0 18:31	,



